

UHF Variable Capacitance Diode

FEATURES

- · Excellent linearity
- Excellent matching to 0.5% DMA
- · Very small plastic SMD package
- C28: 1.9 pF; ratio: 10.
- · Low series resistance.

APPLICATIONS

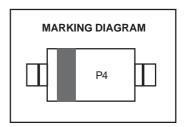
- Electronic tuning in UHF television tuners.
- · VCO.

DESCRIPTION

The BB134 is a variable capacitance diode fabricated in planar technology, and encapsulated in the SOD323 very small plastic SMD package.

The excellent matching performance is achieved by a direct matching assembly procedure. The unmatched type, BB135 has the same specification.







LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | MIN. | MAX. | UNIT | |
|------------------|--------------------------------|-----------------|------|------|--|
| V_R | continuous reverse voltage | - | 30 | V | |
| I _F | continuous forward current | - | 20 | mA | |
| T _{stg} | storage temperature | - 55 | +150 | °C | |
| T_{j} | operating junction temperature | - 55 | +125 | °C | |

ELECTRICAL CHARACTERISTICS

T_j = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------|-------------------------|--|------|------|------|
| lr | reverse current | V _R = 30 V; see Fig.2 | _ | 10 | nA |
| | | $V_R = 30 \text{ V}; T_j = 85 ^{\circ}\text{C}; \text{ see Fig.2}$ | _ | 200 | nA |
| rs | diode series resistance | f = 470 MHz; note | _ | 0.75 | Ω |
| Cd | diode capacitance | V _R = 0.5 V; f = 1 MHz; see Figs 1 and 3 | 17.5 | 21 | рF |
| | | V _R = 28 V;f = 1 MHz; see Figs 1 and 3 | 1.7 | 2.1 | pF |
| Cd(0.5V) | capacitance ratio | f = 1 MHz | 8.9 | 12 | |
| Cd (28V) | | | | | |
| | capacitance matching | VR = 0.5 to 28 V; in a sequence of 4 diodes | _ | 0.5 | % |
| ΔCd | | (gliding) | | | |
| Cd | | VR= 0.5 to 28 V; in a sequence of 15 diodes | - | 2 | % |
| | | (gliding) | | | |

Note

1. VR is the value at which Cd = 9 pF.



BB134

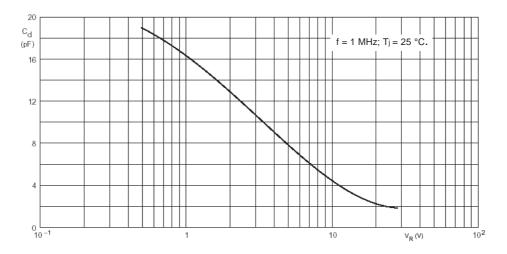


Fig.1 Diode capacitance as a function of reverse voltage; typical values.

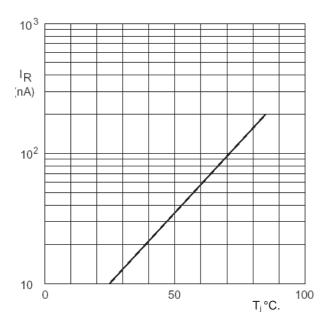


Fig.2 Reverse current as a function of junction temperature; maximum values.

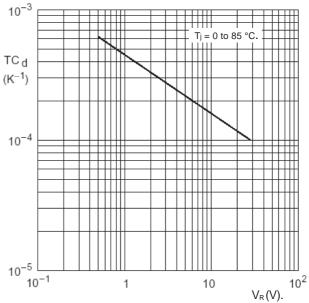


Fig.3 Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.